

# Report on **session 3A**

« New EM developments »

# 7 talks

<b>Firsov and Remizovich effects for low energy low angle proton scattering simulation</b>	<i>MANTERO, Alfonso et al.</i>	
<b>New evaluated PIXE model from ANSTO</b>	<i>GUATELLI, Susanna</i>	
<i>Aula Magna, Ferrara</i>		14:15 - 14:30
<b>New developments of MicroElec processes for low-energy electron transport in Al, Ag and Si</b>	<i>INGUIMBERT, Christophe</i>	
<b>Flagged uniform particle split for Geant4-DNA</b>	<i>RAMOS-MENDEZ, Jose</i>	
<i>Aula Magna, Ferrara</i>		14:45 - 15:00
<b>MPEXS-DNA, a GPU implementation of Geant4-DNA</b>	<i>OKADA, Shogo</i>	
<i>Aula Magna, Ferrara</i>		15:00 - 15:15
<b>A Geant4 application for flexible and extendable DNA geometries incorporating physical and chemical genome damage</b>	<i>LAMPE, Nathanael</i>	
<b>Evaluation of radio-induced DNA damages simulating the physical, physico-chemical and chemical stages with Geant4-DNA</b>	<i>MEYLAN, Sylvain</i>	

# 1) A model for grazing angles soft proton scattering

A. Mantero, P. Dondero et al.

- @ 250 keV, Remizovich and SS consistent with exp data except below  $< 1$  deg.
- SS is the closest to the observation for LowEn, BUT
  - Energy loss is 10 times lower
- MSC good for high energy, both for scattering and energy loss
- @ “large” incident angles all the models are consistent
  - the angular distribution does not depend on p energy
- Firsov ( $\varphi = 0$  Remizovich integration) overestimates 10 times exp data
- no differences are found between the EM opt3 and opt4 list multiple scattering settings.

More to do:

- **Full Remizovich implementation**
- Computing efficiency
- Geant4 integration

More work needed:

- Ad-Hoc measurements
  - Structures
  - Funding



# 2) The ANSTO Evaluated PIXE Model

CMRP: S. Guatelli and S. Bakr, ANSTO: D. Cohen and R. Siegele, Swhard:  
A. Mantero and P. Dondero, CENBG: S. Incerti

- New project
- Import in Geant4 the ANSTO Evaluated PIXE model
  - By J. Crawford, D. Cohen, R. Siegele, G. Doherty, A. Atanacio
  - Up to 5 MeV proton energy
  - Data available also for deuterium and helium as incident particles
  - Targets with Z between 6 and 92
  - Data provided within a self-consistent database, validated against experimental measurements
- Compare the alternative Geant4 PIXE models against experimental measurements of ANSTO micro-PIXE facility

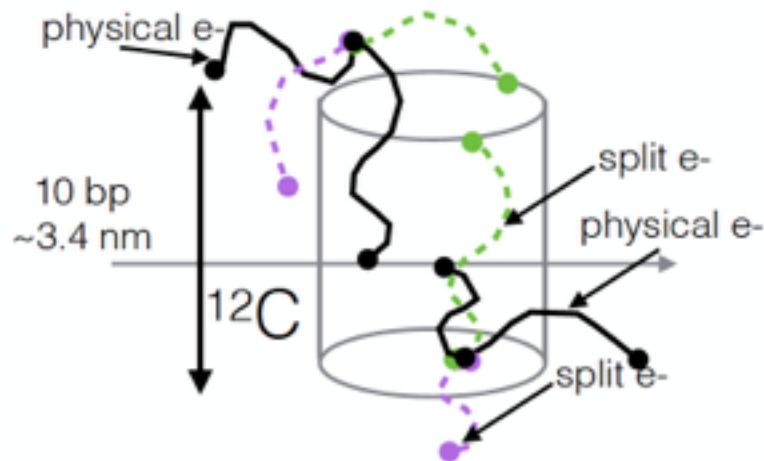
# 3) New developments for MicroElec (Al, Ag, Si)

C. Inguibert, M. Raine

			Status	On going work
<b>Date</b>	2011	June 2012	<b>September 2016</b>	
<b>Material</b>	Al	Si	<b>Si, Al implemented</b> Cross section also calculated for Ag	Ag must be tabulated in MicroElec format
<b>Energy range</b>	10 eV – 5 keV	16,7 eV–100 MeV		
<b>Inelastic model</b>	<b>Specific for each interaction in Al.</b> ~4 eV	GLOBAL Dielectric function Formalism <b>16,7 eV</b>	<b>Inelastic cross section</b> Down to ~1 eV in Si, Al	
<b>Elastic model</b>	Mott-ELSEPA <b>10 eV but all Z</b> [4]	ICRU [6] database <b>5eV for Si only</b>	<b>Elastic cross section</b> Down to 5 eV in Si and Al	Ag must be tabulated in MicroElec format
<b>Geometry</b>	No complex 3D	G4 3D	<b>Available for all Z (NIST)</b>	
<b>Material interfaces</b>	Vacuum/Al + surface plasmon	<b>none</b>	<b>Some comparisons with experimental electron secondary emission yield have been performed</b>	<b>Vacuum/material interface not yet included</b>
<b>Phonons</b>	Simplistic approach	<b>none</b>		<b>Phonons not yet implemented</b>
<b>Observables</b>	<b>Secondary Electron Emission</b> -SEE Yield -Energetic spectrum -Angular distribution	User defined Track structure of heavy ions		

## 4) Flagged uniform particle split for Geant4-DNA

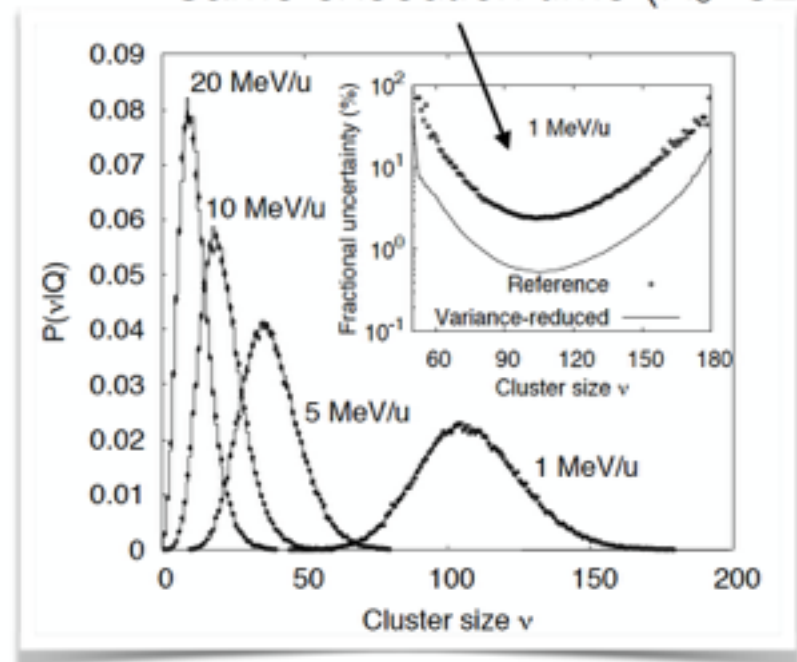
J. Ramos-Mendez, B. Faddegon



- This study showed that the flagged uniform particle split allows to achieve significant improvement of the computational efficiency of Geant4-DNA simulations without compromising the accuracy.
- For protons, the relative efficiency ranged from **50 to 350** (less complex scoring, high to low LET). For carbon ions, the relative efficiency ranged from about **45 to 55** (simple scoring, high to low LET). In both scenarios, the relative differences between variance-reduced and reference simulations were within the 2% within the statistical uncertainty.

- Uniform splitting is applied to  $e^-$ \_G4DNA Ionisation via G4WrapperProcess
- A unique flag (integer number) is assigned to each new split particle.
- This flag must be **inherited** to all subsequent secondaries.
- Use this flag to classify all the tracks independently

Same execution time ( $N_s=32$ )



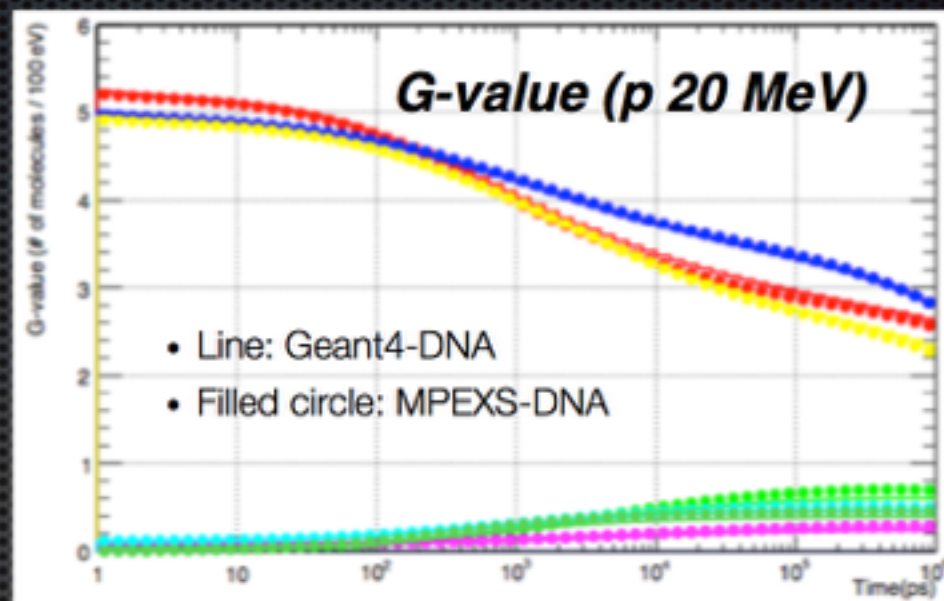


# 5) MPEXS-DNA, a GPU implementation of Geant4-DNA

## Summary

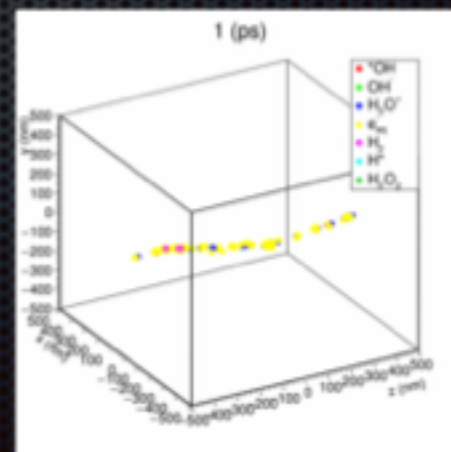
S. Okada et al.

- DNA Physics and Chemical simulation can be run on GPU
- Geant4-DNA processes are implemented in CUDA
- MPEXS-DNA have the same accuracy as Geant4-DNA



- **Achieve up to 200 times speedup againsts single-core CPU**
- ~ 2.5 days (CPU) -> **~ 20 min. (GPU)** (ex. p 20 MeV, 10k events)

	e- 10 keV	e- 750 keV	p 20 MeV
Water phantom size	1 x 1 x 1 um	5 x 5 x 5 um	1 x 1 x 1 um
Average # of molecules generated at 1 ps	419	126	347
Process time (Geant4-DNA 10.02 p01)	30.6 sec / event	5.01 sec / event	22.1 sec / event
Process time (MPEXS-DNA)	0.197 sec / event	0.0336 sec / event	0.115 sec / event
Speedup factor	<b>155x</b>	<b>149x</b>	<b>192x</b>

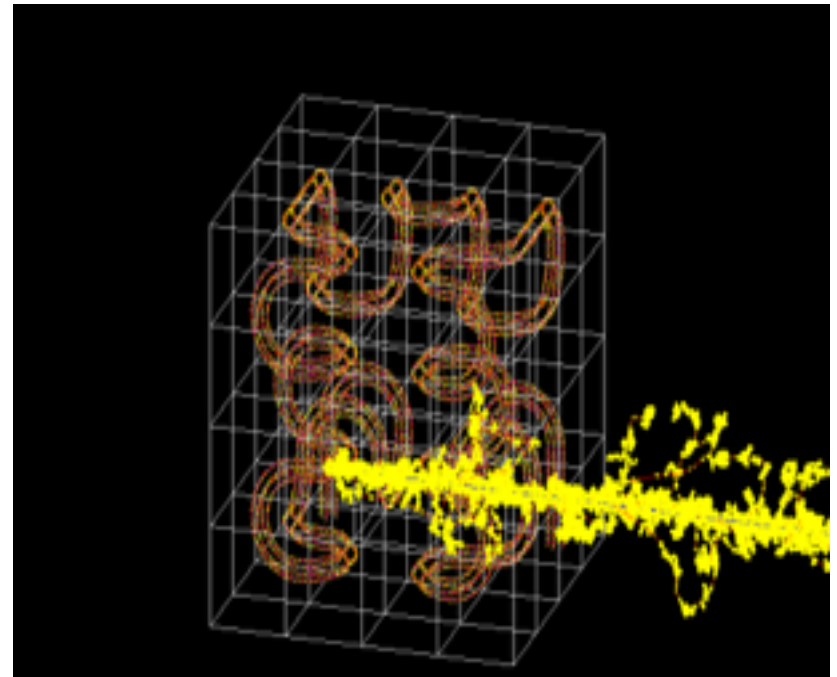


# 6) The MolecularDNA Application

N. Lampe

- A monolithic application simulating direct and indirect DNA damage
- Flexible specification of DNA geometries
  - Ships with bacterial DNA
  - Extendable to chromatin, plasmids, test DNA geometries, all without touching C++
- Coming early 2017

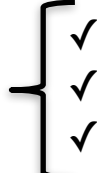
1 MeV protons travelling through a simple continuous DNA model





## 7) Evaluation of radio-induced DNA damages simulating the physical, physico-chemical and chemical stages with Geant4-DNA

S. Meylan

- DnaFabric 
  - ✓ Generate/Edit/Save complex DNA geometries
  - ✓ Visualize
  - ✓ Export to Geant4-DNA (“`.fab2g4dna`” file)
- Simulate the physical, physico-chemical and chemical stages with such geometrical models.
- Results are consistent with experimental data
- Criteria associated with the creation of DNA damages are not “set in stone”:
  - Direct SSB threshold or linear acceptance probability
  - Duration of the chemical stage (by default 2.5 ns).

### What will be delivered:

- ✓ A user-application to show how to introduce a DNA geometrical model in a chemical simulation.
- ✓ To do so, some of the Geant4 modifications should be integrated.